Unitized Semiconductor Devices - Page 1 of 1



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Inclosure	Material:

Metal

**Overall Length:** 

0.185 inches

## **Terminal Length:**

0.500 inches

## **Overall Diameter:**

0.370 inches

**Component Name And Quantity:** 

3 transistor

### Mounting Method:

Terminal

### **Terminal Circle Diameter:**

0.230 inches

### Features Provided:

Hermetically sealed case

### Semiconductor Material:

Silicon all transistor

## Voltage Rating In Volts Per Characteristic:

15.0 collector to emitter voltage/static/base open all transistor and 30.0 collector to base voltage/static/emitter open all transistor and 5.0

emitter to base voltage, static, collector open all transistor

## **Current Rating Per Characteristic:**

50.00 milliamperes source cutoff current all transistor

## **Power Rating Per Characteristic:**

450.0 milliwatts small-signal input power, common-collector preset all transistor

#### **Transfer Ratio:**

200.0 static forward current transfer ratio, common-emitter all transistor

## Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

#### **Special Features:**

All transistor junction pattern arrangement: npn

# Terminal Type And Quantity:

12 uninsulated wire lead

# Shelf Life:

N/a

# Unit Of Measure:

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Demilitarization:

No

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